

# NCE15TD120BT

#### 1200V, 15A, Trench FS II Fast IGBT

#### **General Description:**

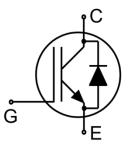
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 1200V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

#### **Features**

- Trench FSII Technology offering
- Very low V<sub>CE(sat)</sub>
- Positive temperature coefficient in V<sub>CE(sat)</sub>
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

#### **Application**

- Inverters
- Motor drives
- Converter



Schematic diagram

#### **Package Marking and Ordering Information**

Device	Device Package	Device Marking
NCE15TD120BT	TO-247	NCE15TD120BT



TO-247

### **Absolute Maximum Ratings (Tc=25°C unless otherwise noted)**

Symbol	Parameter	Value	Units
Vces	Collector-Emitter Voltage	1200	V
$V_{GES}$	Gate- Emitter Voltage	±30	V
la la	Collector Current	30	А
lc	Collector Current @T <sub>C</sub> = 100 °C	15	А
I <sub>Cpuls</sub>	Pulsed Collector Current, tp limited by T <sub>jmax</sub>	45	А
-	turn off safe operating area, V <sub>CE</sub> =1350V, Tj=150°C	45	А
l <sub>F</sub>	Diode Continuous Forward Current @Tc = 100 °C	15	А
I <sub>FM</sub>	Diode Maximum Forward Current	45	А
D-	Power Dissipation @ T <sub>C</sub> = 25°C	300	W
P <sub>D</sub>	Power Dissipation @T <sub>C</sub> = 100 °C	150	W
T <sub>J</sub> ,T <sub>stg</sub>	Operating Junction and Storage Temperature Range	-55 to +175	°C
TL	Maximum Temperature for Soldering	260	°C



## NCE15TD120BT

**PbFreeProduct** 

#### **Thermal Characteristic**

Symbol	Parameter	Value	Units
Rejc	Thermal Resistance, Junction to case for IGBT	0.50	°C/W
Rejc	Thermal Resistance, Junction to case for Diode	0.86	°C/W
R <sub>θ</sub> ЈА	Thermal Resistance, Junction to Ambient	40	°C/W

#### Electrical Characteristics (Tc=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Value			
			Min.	Тур.	Max.	Units
Static Chara	cteristics	•				
V <sub>(BR)CES</sub>	Collector-Emitter Breakdown Voltage	V <sub>GE</sub> =0V,I <sub>CE</sub> =1mA	1200			V
Ices	Collector-Emitter Leakage Current	V <sub>GE</sub> =0V,V <sub>CE</sub> =1350V			5	uA
I <sub>GES(F)</sub>	Gate to Emitter Forward Leakage	V <sub>GE</sub> =+30V,V <sub>CE</sub> =0V			200	nA
I <sub>GES(R)</sub>	Gate to Source Reverse Leakage	V <sub>GE</sub> =-30V,V <sub>CE</sub> =0V			200	nA
M	Callegater Fraitter Cathurstine Voltage	V <sub>GE</sub> =15V,I <sub>C</sub> =15A, Tj=25°C		1.55	1.80	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	V <sub>GE</sub> =15V,I <sub>C</sub> =15A, Tj=150°C		1.80		V
$V_{GE(th)}$	Gate Threshold Voltage	I <sub>C</sub> =1mA, V <sub>CE</sub> =V <sub>GE</sub>	5.0		6.5	V
Dynamic Ch	aracteristics					
Cies	Input Capacitance	V <sub>CE</sub> =30V,V <sub>GE</sub> =0V, f=1MHz		1430		pF
Coes	Output Capacitance			35		
Cres	Reverse Transfer Capacitance			25		
Qg	Total Gate Charge			90		nC
Qge	Gate to Emitter Charge	Vcc=600V, Ic=15A V <sub>GE</sub> =15V		11		nC
Qgc	Gate to Collector Charge	, VGL-10V		58		nC
Switching Cl	naracteristics					
t <sub>d(ON)</sub>	Turn-on Delay Time			19		
t <sub>r</sub>	Rise Time			17		20
t <sub>d(OFF)</sub>	Turn-Off Delay Time	Vce=600V,Ic=15A		170		ns
t <sub>f</sub>	Fall Time	$V_{GE}=0/15V$ , $R_g=8\Omega$		18		
Eon	Turn-On Switching Loss	Inductive Load		0.9		
E <sub>off</sub>	Turn-Off Switching Loss			0.6		mJ
Ets	Total Switching Loss			1.5		

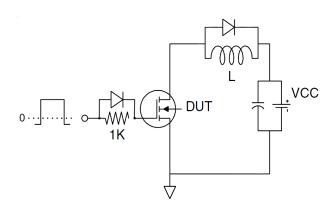
#### Electrical Characteristics of the Diode (Tc= 25°C unless otherwise specified):

Symbol	Parameter	Test Conditions	Rating			Units
			Min.	Тур.	Max.	Ullits
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> =15A		2.2	3.0	V
Trr	Reverse Recovery Time	I <sub>F</sub> =15A, di/dt=200A/us		120		ns
I <sub>RRM</sub>	Diode Peak Reverse Recovery Current			12		Α
Qrr	Reverse Recovery Charge			0.72		uC
Pulse width t <sub>tp</sub> :	Pulse width $t_{tp} \le 380 \mu s, \delta \le 2\%$					

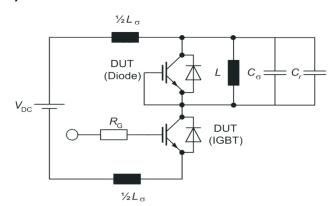


#### **Test Circuit**

#### 1) Gate Charge Test Circuit

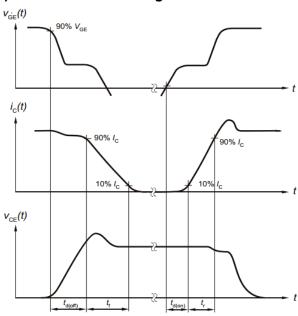


#### 2) Switch Time Test Circuit

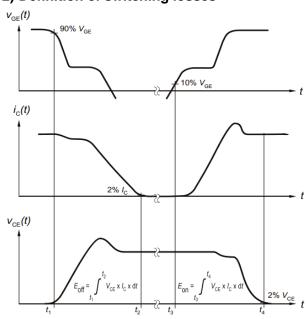


#### **Switching characteristics**

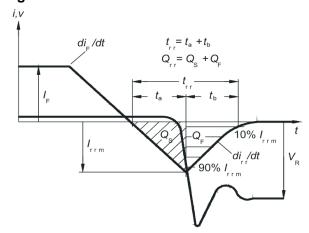
#### 1) Definition of switching times



#### 2) Definition of switching losses



### 3) Definition of diode switching characteristics





#### **Typical Electrical and Thermal Characteristics**

#### **Figure 1 Output Characteristics**

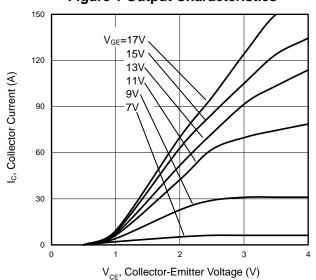
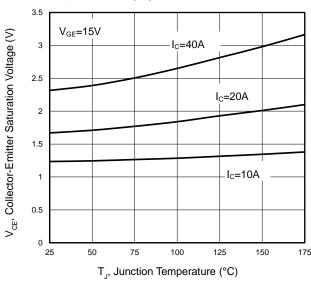


Figure 3 V<sub>CE(sat)</sub> vs. Case Temperature



**Figure 5 Capacitance Characteristics** 

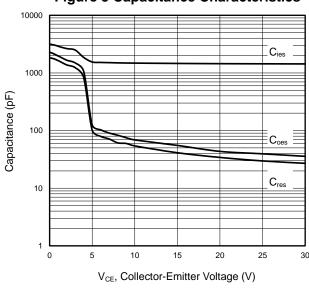


Figure 2 Transfer Characteristics

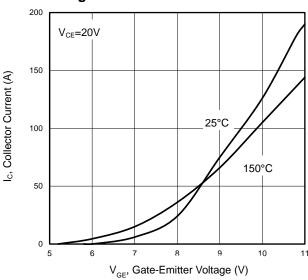


Figure 4 Saturation Voltage vs. V<sub>GE</sub>

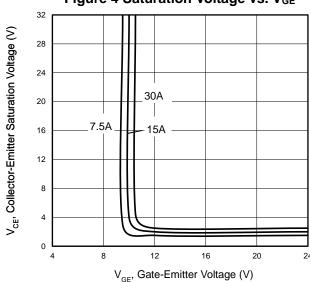
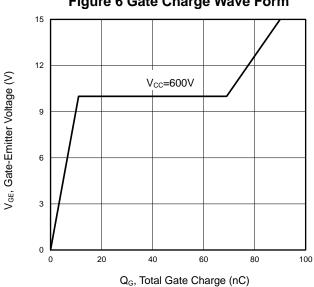
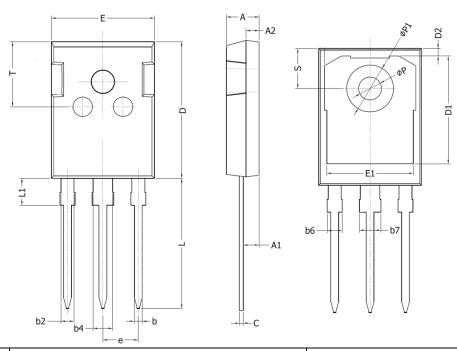


Figure 6 Gate Charge Wave Form





# **TO-247-3L Package Information**



Comb al	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.90	5.10	0.193	0.201	
A1	2.31	2.51	0.091	0.099	
A2	1.9	2.1	0.075	0.083	
b	1.16	1.26	0.046	0.050	
b2	1.96	2.06	0.077	0.081	
b4	2.96	3.06	0.117	0.120	
b6	-	2.25	-	0.089	
b7	-	3.25	-	0.128	
С	0.59	0.66	0.023	0.026	
D	20.90	21.10	0.823	0.831	
D1	16.25	16.85	0.640	0.663	
D2	1.05	1.35	0.041	0.053	
E	15.70	15.90	0.618	0.626	
E1	13.10	13.50	0.516	0.531	
е	5.436	BSC	0.214 BS	С	
L	19.80	20.10	0.780	0.791	
L1	-	4.30	-	0.169	
Р	3.40	3.60	0.134	0.142	
P1	7.00	7.40	0.276	0.291	
S	6.05	6.25	0.238	0.246	
Т	9.80	10.20	0.386	0.402	



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